DATA SHEET =



MB1502/MB1502H

SERIAL INPUT PLL FREQUENCY SYNTHESIZER

LOW POWER SERIAL INPUT PLL SYNTHESIZER WITH 1.1 GHz PRESCALER

The Fujitsu MB1502/MB1502H, utilizing Bi-CMOS technology, are single chip serial input PLL synthesizers with pulse-swallow function. Each MB1502/MB1502H contains a 1.1GHz two modulus prescaler that can select of either 64/65 or 128/129 divide ratio, control signal generator, 16-bit shift register, 15-bit latch, programmable reference divider (binary 14-bit programmable reference counter), 1-bit switch counter, phase comparator with phase conversion function, charge pump, crystal oscillator, 19-bit shift register, 18-bit latch, programmable divider (binary 7-bit swallow counter and binary 11-bit programmable counter) and analog switch to speed up lock up time.

They operate at a supply voltage of 5V typ. and achieves a very low supply current of 8mA typ. realized through the use of Fujitsu Advanced Process Technology.

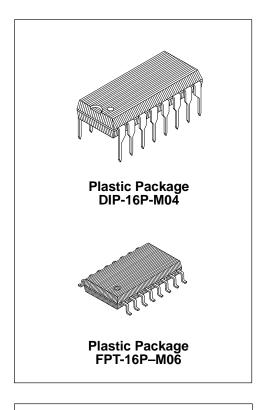
FEATURES

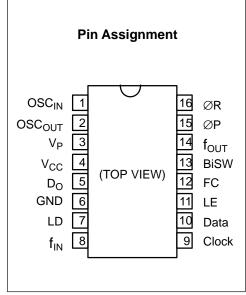
- High operating frequency: f_{IN MAX}=1.1GHz (V_{IN MIN}=10dBm)
- Pulse swallow function: 64/65 or 128/129
- Low supply current: I_{CC}=8mA typ.
- Serial input 18-bit programmable divider consisting of:
 - Binary 7-bit swallow counter: 0 to 127
 - Binary 11-bit programmable counter: 16 to 2047
- Serial input 15-bit programmable reference divider consisting of:
 - Binary 14-bit programmable reference counter: 8 to 16383
 - 1-bit switch counter (SW) sets divide ratio of prescaler
- On-chip analog switch achieves fast lock up time
- 2 types of phase detector output
 - On-chip charge pump (Bipolar type)
 - Output for external charge pump
- Wide operating temperature: –40°C to +85°C
- 16-pin Plastic DIP Package (Suffix: —P)
 16-pin Plastic Flat Package (Suffix: —PF)

ABSOLUTE MAXIMUM RATINGS (See NOTE)

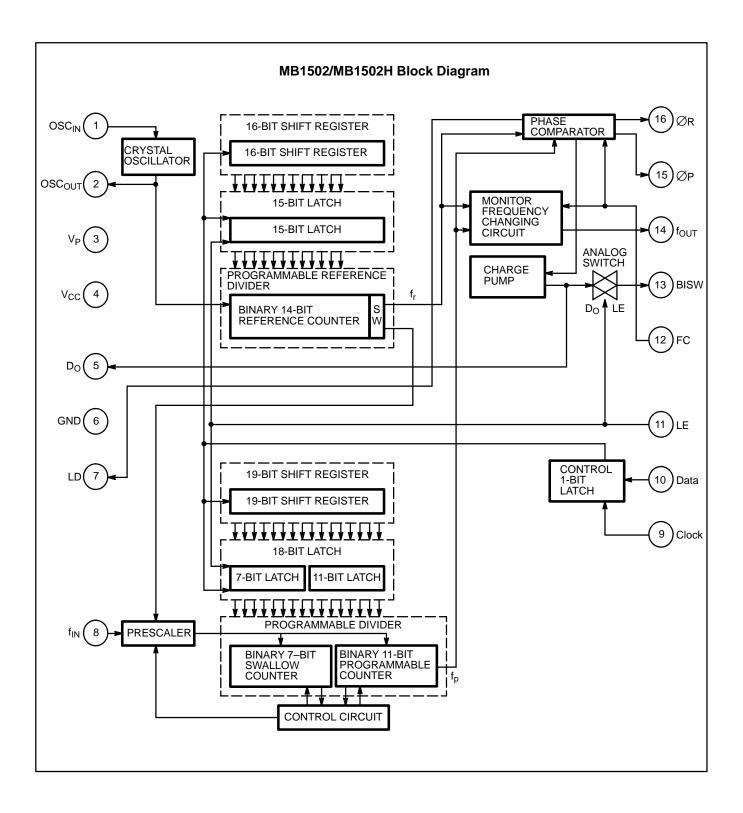
Rating	Symbol	Value	Unit
Dower Cumply Voltage	V _{CC}	-0.5 to +7.0	V
Power Supply Voltage	V _P	V _{CC} to 10.0	V
Output Voltage	V _{OUT}	-0.5 to V _{CC} +0.5	V
Open-drain Voltage	V _{OOP}	-0.5 to 0.8	V
Output Current	I _{OUT}	± 10	mA
Storage Temperature	T _{STG}	-55 to +125	°C

NOTE: Permanent device damage may occur if the above Absolute Maximum RatIngs are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.



PIN DESCRIPTION

Pin No.	Pin Name	1/0	Description
1 2	OSC _{IN} OSC _{OUT}	O	Oscillator input. Oscillator output. A crystal is placed between OSC _{IN} and OSC _{OUT} .
3	V _P	_	Power supply input for charge pump and analog switch.
4	V _{CC}	_	Power supply voltage input.
5	D _O	0	Charge pump output. The characteristics of charge pump is reversed depending upon FC input.
6	GND	_	Ground
7	LD	0	Phase comparator output. Normally this pin outputs high level. While the phase difference of f_r , and f_p exists, this pin outputs low level.
8	f _{IN}	I	Prescaler input. The connection with an external VCO should be AC connection.
9	Clock	I	Clock input for 19-bit shift register and 16-bit shift register. On rising edge of the clock shifts one bit of data into the shift registers.
10	Data	I	Binary serial data input. The last bit of the data is a control bit which specified destination of shift registers. When this bit is high level and LE is high level, the data stored in shift register is transferred to 15-bit latch. When this bit is low level and LE is high level, the data is transferred to 18-bit latch.
11	LE	I	Load enable input (with internal pull up resistor). When LE is high or open, the data stored in shift register is transferred into latch depending upon the control bit. At the time, internal charge pump output to be connected to BISW pin because internal analog switch becomes ON state.
12	FC	I	Phase select input of phase comparator (with internal pull up resistor). When FC is low level, the characteristics of charge pump, phase comparator is reversed. FC input signal is also used to control fOUT pin (test pin) output level for f _r or f _p .
13	BISW	0	Analog switch output. Usually BISW pin is set high-impedance state. When internal analog switch is ON (LE pin is high level), this pin outputs internal charge pump state.
14	fоит	0	Monitor pin of phase comparator input. f_{OUT} pin outputs either programmable reference divider output (f_r) or programmable divider output (f_p) depending upon FC pin input level.
15 16	ØP ØR	0	Outputs for external charge pump. The characteristics are reversed according to FC input. ØP pin is N-channel open drain output.

FUNCTIONAL DESCRIPTIONS

SERIAL DATA INPUT

Serial data input is achieved by three inputs, such as Data pin, Clock pin and LE pin. Serial data input controls 15-bit programmable reference divider and 18-bit programmable divider, respectively.

Binary serial data is input to Data pin.

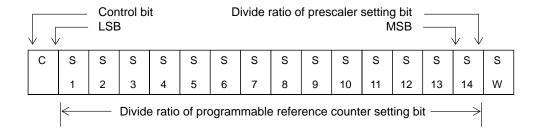
On rising edge of clock shifts one bit of serial data into the internal shift registers and when load enable pin is high level or open, stored data is transferred into latch depending upon the control bit.

Control data "H" data is transferred into 15-bit latch.

Control data "L" data is transferred into 18-bit latch.

PROGRAMMABLE REFERENCE DIVIDER

Programmable reference divider consists of 16-bit shift register, 15-bit latch and 14-bit reference counter. Serial 16-bit data format is shown below.



14-BIT PROGRAMMABLE REFERENCE COUNTER DIVIDE RATIO

Divide Ratio	S	S	S	S	S	S	S	S	S	S	S	S	S	S
R	14	13	12	11	10	9	8	7	6	5	4	3	2	1
8	0	0	0	0	0	0	0	0	0	0	1	0	0	0
9	0	0	0	0	0	0	0	0	0	0	1	0	0	1
•	•	•	•	•	•	•	•	•	•	•	•	•	•	•
16383	1	1	1	1	1	1	1	1	1	1	1	1	1	1

NOTES: Divide ratio less than 8 is prohibited.

Divide ratio: 8 to 16383

SW: This bit selects divide ratio of prescaler.

SW=H: 64
SW=L:128
S1 to S14: These bits select divide ratio of programmable reference divider.

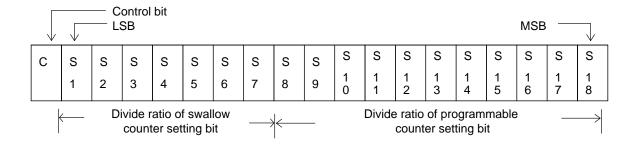
C: Control bit (sets as high level).

Data is input from MSB side.

PROGRAMMABLE DIVIDER

Programmable divider consists of 19-bit shift register, 18-bit latch, 7-bit swallow counter and 11-bit programmable counter.

Serial 19-bit data format is shown on following page.



7-BIT SWALLOW COUNTER DIVIDE RATIO

Divide Ratio	S	S	S	S		S	S
Α	7	6	5	4	3	2	1
0	0	0	0	0	0	0	0
1	0	0	0	0	0	0	1
•	•	•	•	•	•	•	•
127	1	1	1	1	1	1	1

NOTE: Divide ratio: 0 to 127

11-BIT PROGRAMMABLE COUNTER DIVIDE RATIO

Divide	S	S	S	S	S	S	S	S	S	S	S
Ratio N	1 8	1 7	1 6	1 5	1 4	1 3	1 2	1	1 0	9	8
16	0	0	0	0	0	0	1	0	0	0	1
17	0	0	0	0	0	0	1	0	0	0	1
•	•	•	•	•	•	•	•	•	•	•	•
2047	1	1	1	1	1	1	1	1	1	1	1

NOTES: Divide ratio less than 16 is prohibited.

Divide ratio: 16 to 2047
S1 to S7: Swallow counter divide ratio setting bit. (0 to 127)
S8 to S18: Programmable counter divide ratio setting bit. (16 to 2047)

C: Control bit (sets as low level). Data is input from MSB side.

PULSE SWALLOW FUNCTION

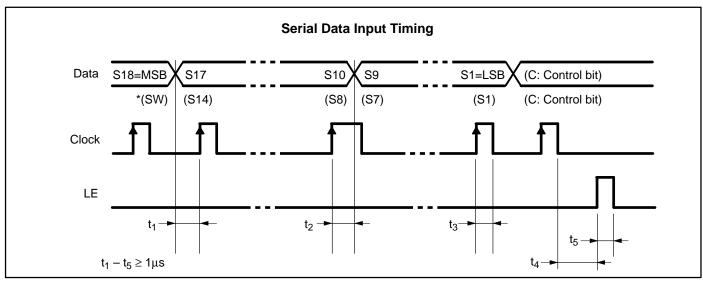
[(PxN)+A] $x f_{osc} \div R$ $f_{vco} =$

Output frequency of external voltage controlled oscillator (VCO) f_{VCO} : N: Preset divide ratio of binary 11-bit programmable counter (16 to 2047) Preset divide ratio of binary 7-bit swallow counter (0≤A≤127, A<N) A: Output frequency of the external reference frequency oscillator fosc:

R: Preset divide ratio of binary 14-bit programmable reference counter (8 to 16383)

P: Preset modulus of external dual modulus prescaler (64 or 128)

5



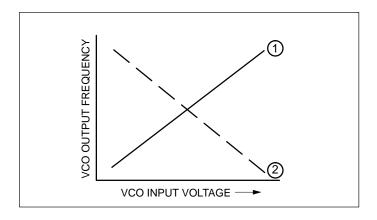
NOTES: Parenthesis data is used for setting divide ratio of programmable reference divider. On rising edge of clock shifts one bit of data in the shift register.

PHASE CHARACTERISTICS

FC pin is provided to change phase characteristics of phase comparator. Characteristics of internal charge pump output level (D_0), phase comparator output level (D_0 R, D_0 R) are reversed depending upon FC pin input level. Also, monitor pin (D_0 R) output level of phase comparator is controlled by FC pin input level. The relation between outputs (D_0 , D_0 R, D_0 R) and FC input level are shown below.

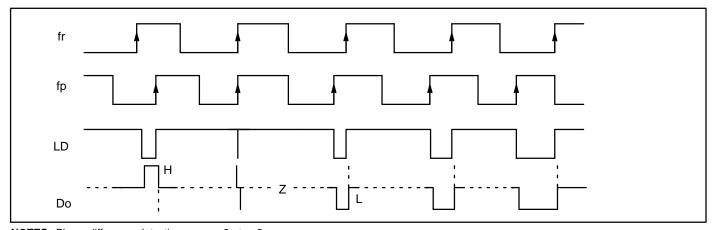
		FC=H c	r open		FC=L					
	Do	ØR	Ø₽	f _{OU} T	Do	ØR	Ø₽	f _{OU} T		
$f_r > f_p$	Н	L	L	(f _r)	L	Н	Z	(f _p)		
$f_r < f_p$	L	Н	Z	(f _r)	Н	L	L	(f _p)		
$f_r = f_p$	Z	L	Z	(f _r)	Z	L	Z	(f _p)		

Note: Z = (High impedance)



VCO CHARACTERISTICS Depending upon VCO characteristics, FC pin should be set accordingly:

- When VCO characteristics are like 1,
 FC should be set High or open circuit;
- When VCO characteristics are like 2, FC should be set Low.



NOTES: Phase difference detection range: -2π to $+2\pi$

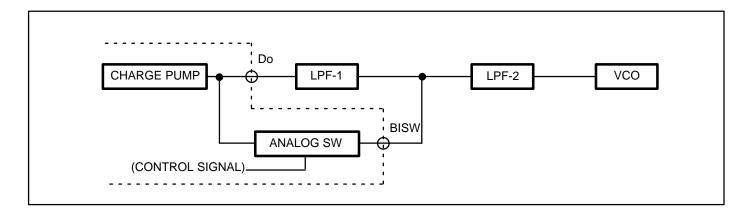
Spike appearance depends on charge pump characteristics. Also, the spike is output in order to diminish dead band. When $f_r > f_p$ or $f_r < f_p$, spike might not appear depending upon charge pump characteristics.

ANALOG SWITCH

ON/OFF of analog switch is controlled by LE input signal. When the analog switch is ON, internal charge pump output (DO) to be connected to BISW pin. When the analog switch is OFF, BISW pin is set to high-impedance state.

LE=H (Changing the divide ratio of internal prescaler): Analog switch=ON LE=L (Normal operating mode): Analog switch=OFF

LPF time constant is decreased in order to insert a analog switch between LPF1 and LPF2 when channel of PLL is changing. Thus, lock up time is decreased, that is, fast lock up time is achieved.



RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Unit			
Parameter	Symbol	Min	Min Typ		Oilit	
Davies Complex Veltage	V _{CC}	4.5	5.0	5.5	V	
Power Supply Voltage	V _P	V _{CC}	V _P	8.0	V	
Input Voltage	VI	GND		V _{CC}	V	
Operating Temperature	T _A	-40		85	°C	

ELECTRICAL CHARACTERISTICS

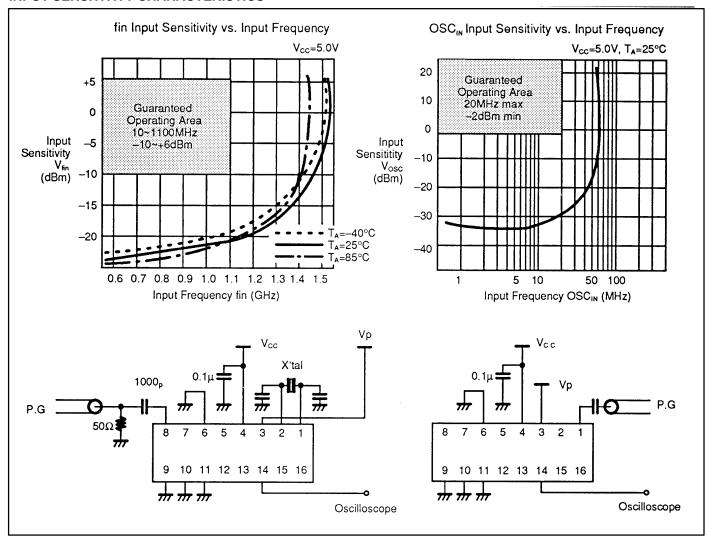
(Vcc=4.5 to 5.5V, TA=-40 to +85°C, unless otherwise noted.)

Parameter		Cumb al	Con	dition		Value			
		Symbol				Тур	Max	Unit	
Power Supply Current		Icc	N	ote 1		8.0	12.0	mA	
• " =	f _{in}	f _{in}	N	ote2	10		1100	MHz	
Operating Frequency	OSCIN	fosc				12	20	MHz	
1 40 10 10	f _{in}	V _{fin}			-10		6	dBm	
Input Sensitivity	OSCIN	Vosc			0.5			V _{PP}	
High-level Input Voltage	Except fin	V _{IH}			V _{CC} x0.7			V	
Low-level Input Voltage	and OSC _{IN}	V _{IL}					V _{CC} x0.3	V	
High-level Input Current	Data	I _{IH}				1.0		μΑ	
Low-level Input Current	Clock	I _{IL}				-1.0		μΑ	
	OSC _{IN}	losc				±50		μΑ	
Input Current	LE, FC	I _{LE}				-60		μΑ	
High-level Output Voltage	Except D _O	V _{OH}	V _{CC}	₅ = 5 V	4.4			V	
Low-level Output Voltage	and OSC _{OUT}	V _{OL}					0.4	V	
N-channel Open Drain Cutoff Current	$D_{O}, \varnothing P$	I _{OFF}	$V_P = V_{OOP}$	CC to 8V GND to 8V			1.1	μΑ	
	Except D _O	I _{OH}			-1.0			mA	
Output Current	and OSC _{OUT}	I _{OL}			1.0			mA	
High-level Output Current		I _{DDH}			-0.8	-1.5		mA	
Low-level Output Current	Do	I _{DOL}	MB1502	V _{CC=} 5V,	11	22		mA	
High-level Output Current	Do	I _{DOLH}		V _{P=} 8V, T _{A=} 25∘ _C	-1.4	-2.4		mA	
Low-level Output Current		I _{DOLH}	MB1502H		4.5	10		mA	
Analog Switch On Resistor	ı	R _{ON}				25		Ω	

NOTE: 1: f in = 1.1GHz, OSC_{IN}=12MHz, V_{cc}=5V. Inputs are grounded and outputs are open. 2: AC coupling. Minimum operating frequency is measured when a capacitor 1000pF is connected.

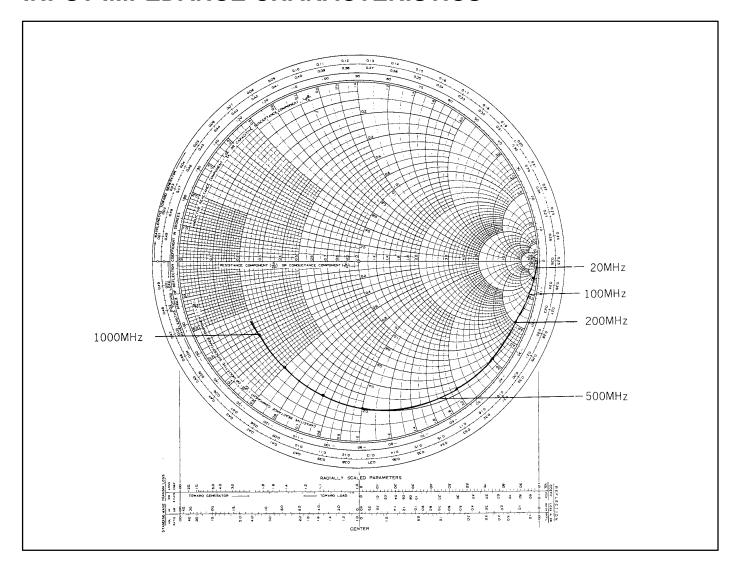
TYPICAL CHARACTERISTICS CURVES

INPUT SENSITIVITY CHARACTERISTICS

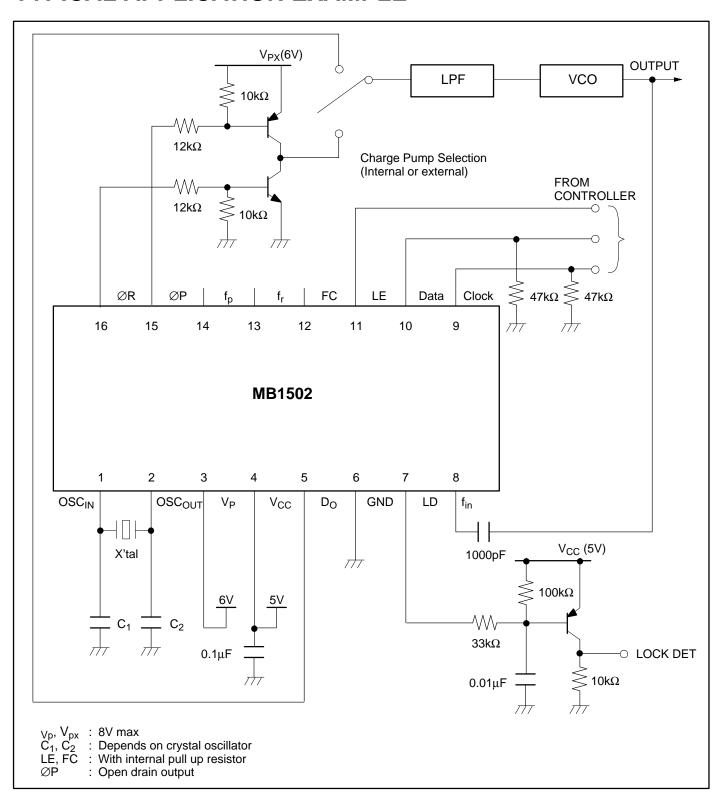


DO PIN OUTPUT CURRENTCURVES (TYPICAL)								

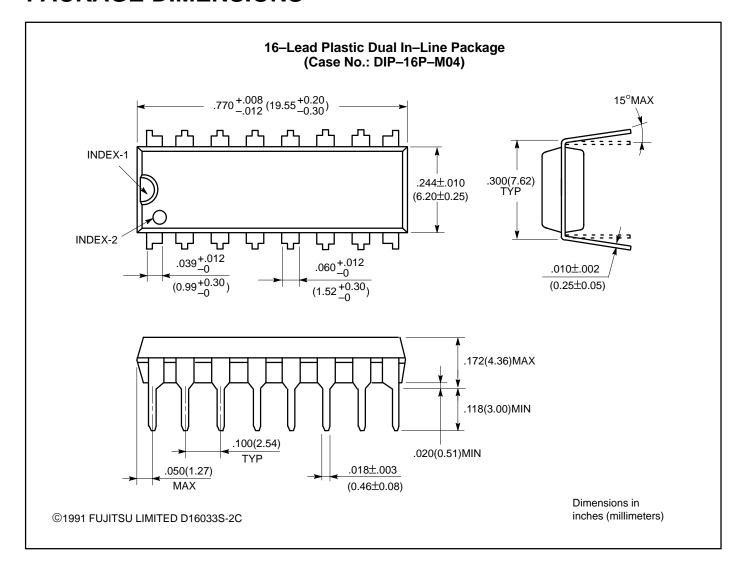
INPUT IMPEDANCE CHARACTERISTICS

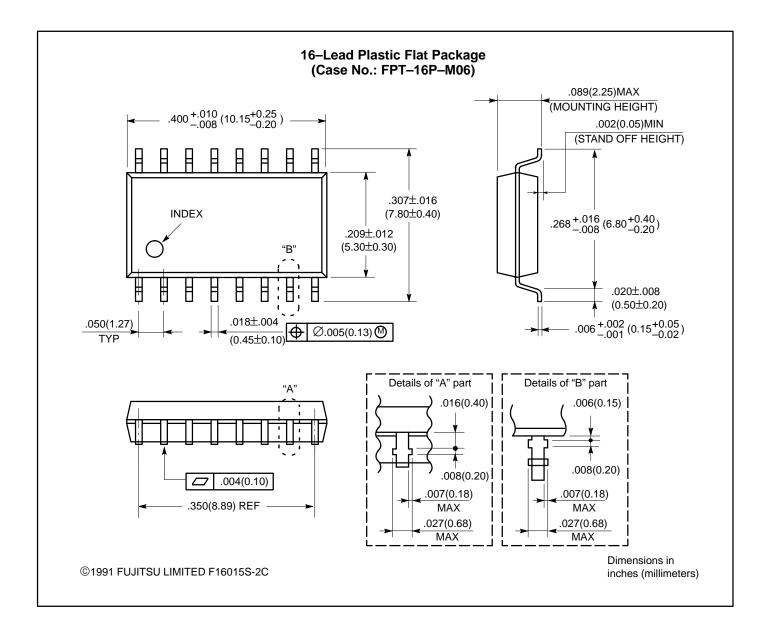


TYPICAL APPLICATION EXAMPLE



PACKAGE DIMENSIONS





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